NSN 5962-01-253-0205

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Body Length:	
1.290 inches	
Body Width:	
Between 0.500 inch	es and 0.610 inches
Body Height:	
0.150 inches	
Maximum Power D	Dissipation Rating:
1.02 watts	
Operating Tempur	ature Range:
-55.0/+125.0 degree	es celsius
Storage Tempurat	ure Range:
-65.0/+150.0 degree	es celsius
End Application:	
Radar set an/sps-4	(v) 5
Features Provided	:
Programmable and	hermetically sealed and monolithic and bipolar and 3-state output and high impedance
Inclosure Material	
Ceramic and glass	
Inclosure Configu	ration:
Dual-in-line	
Output Logic Forn	1:
Transistor-transisto	rlogic
Input Circuit Patte	rn:
14 input	
Case Outline Sour	ce And Designator:
D-3 mil-m-38510	
Terminal Surface	Freatment:
Solder	
Voltage Rating An	d Type Per Characteristic:
7.0 volts power sou	Irce
Time Rating Per C	hacteristic:
100.00 nanosecond	s propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	pe:
Rom	
Test Data Docume	nt:
96906-mil-std-883 s	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	d Quantity:
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

